## NSN 5961-00-052-9656

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Inclosure Material:
Metal
Overall Length:
0.802 inches
Terminal Length:
1.500 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-13
Mounting Method:
Terminal and threaded stud
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.442 inches
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
150.0 breakdown voltage, collector-to-base, emitter open and 6.0 emitter to base voltage, static, collector open and 100.0 breakdown
voltage, collector-to-emitter, base open
Current Rating Per Characteristic:
750.00 milliamperes repetitive peak forward current blank and 750.00 milliamperes repetitive peak forward current
Power Rating Per Characteristic:
2.0 watts small-signal input power, common-collector
Transfer Ratio:
20.0 static forward current transfer ratio, common-emitter and 60.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 uninsulated wire lead and 1 threaded stud
Shelf Life:

N/a

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Demilitarization:

No

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